# DMC904F0

### Silicon NPN epitaxial planar type

#### For high frequency amplification

#### Features

- $\bullet$  High forward current transfer ratio  $h_{\text{FE}}$  with excellent linearity
- $\bullet$  High transition frequency  $f_{T}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)
- Marking Symbol: D3

#### Basic Part Number

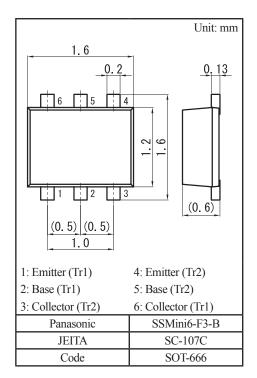
DSC2G02 + DSC2001 (Individual)

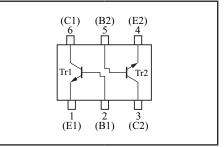
#### Packaging

DMC904F00R Embossed type (Thermo-compression sealing): 8 000 pcs / reel (standard)

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter		Symbol	Rating	Unit	
	Collector-base voltage (Emitter open)	V <sub>CBO</sub>	30	V	
T.1	Collector-emitter voltage (Base open)	V <sub>CEO</sub>	20	V	
Tr1	Emitter-base voltage (Collector open)	V <sub>EBO</sub>	3	V	
	Collector current	I <sub>C</sub>	15	mA	
Tr2	Collector-base voltage (Emitter open)	V <sub>CBO</sub>	60	V	
	Collector-emitter voltage (Base open)	V <sub>CEO</sub>	50	V	
	Emitter-base voltage (Collector open)	V <sub>EBO</sub>	7	V	
	Collector current	I <sub>C</sub>	100	mA	
	Peak collector current	I <sub>CP</sub>	200	mA	
	Total power dissipation	P <sub>T</sub>	125	mW	
Overall	Junction temperature	Tj	150	°C	
	Operating ambient temperature	T <sub>opr</sub>	-40 to +85	°C	
	Storage temperature	T <sub>stg</sub>	-55 to +150	°C	





#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

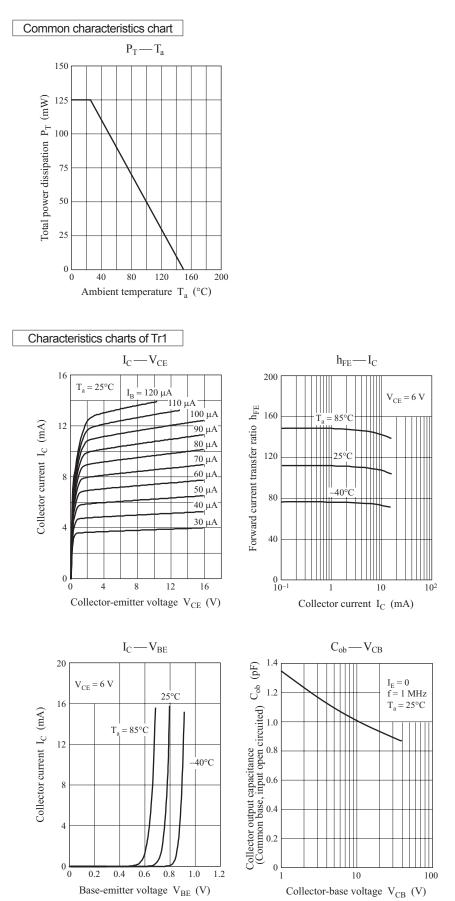
• Tr1

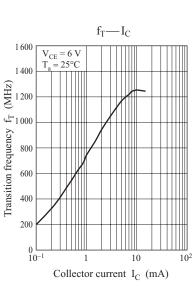
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	30			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	3			V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = 6 V, I_C = 1 mA$		0.72		V
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 6 V, I_C = 1 mA$	65		260	
Transition frequency	f <sub>T</sub>	$V_{CE} = 6 V, I_C = 1 mA$	450	650		MHz
Reverse transfer capacitance (Common emitter)	C <sub>re</sub>	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 10.7 \text{ MHz}$		0.6		pF
Power gain	PG	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 100 \text{ MHz}$		24		dB
Noise figure	NF	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 100 \text{ MHz}$		3.3		dB

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

• Tr2						
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	60			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 2  {\rm mA},  I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	7			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 10 \text{ V}, I_{B} = 0$			100	μΑ
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	210		460	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$		0.13	0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1.5		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.





V<sub>CE(sat)</sub>—I<sub>C</sub>

 $T_a = 85^{\circ}C$ 

Collector current I<sub>C</sub> (mA)

10

 $10^{2}$ 

25°C

1

 $/ I_{\rm B} = 10$ 

10

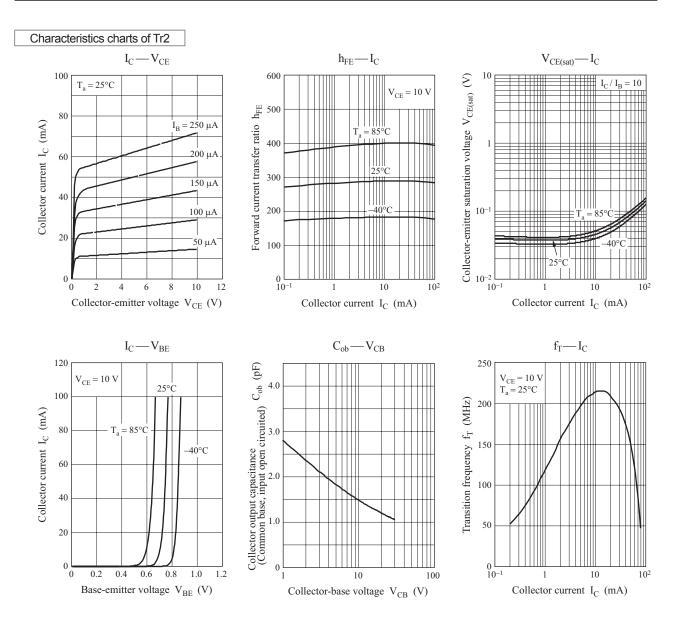
1

10-1

 $10^{-2}$ 

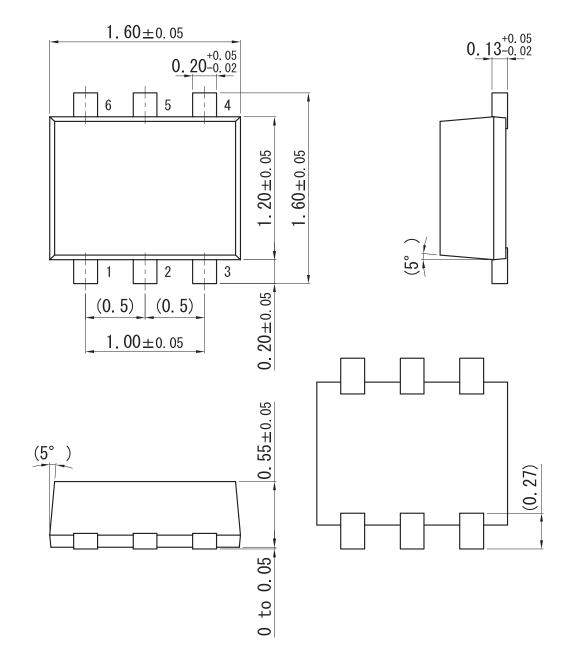
 $10^{-1}$ 

Collector-emitter saturation voltage V<sub>CE(sat)</sub> (V)

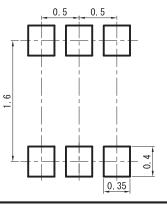


## SSMini6-F3-B

Unit: mm



Land Pattern (Reference) (Unit: mm)



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